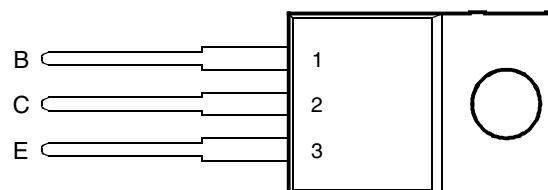


- Designed for Complementary Use with BDW64, BDW64A, BDW64B, BDW64C and BDW64D
- 60 W at 25°C Case Temperature
- 6 A Continuous Collector Current
- Minimum h_{FE} of 750 at 3V, 2 A

TO-220 PACKAGE
(TOP VIEW)

Pin 2 is in electrical contact with the mounting base.

MDTRACA

absolute maximum ratings at 25°C case temperature (unless otherwise noted)

| RATING | | SYMBOL | VALUE | UNIT |
|--|---------------------|-----------|-------------|------|
| Collector-base voltage ($I_E = 0$) | BDW63 | V_{CBO} | 45 | V |
| | BDW63A | | 60 | |
| | BDW63B | | 80 | |
| | BDW63C | | 100 | |
| | BDW63D | | 120 | |
| Collector-emitter voltage ($I_B = 0$) (see Note 1) | BDW63 | V_{CEO} | 45 | V |
| | BDW63A | | 60 | |
| | BDW63B | | 80 | |
| | BDW63C | | 100 | |
| | BDW63D | | 120 | |
| Emitter-base voltage | V_{EB} | | 5 | V |
| Continuous collector current | I_C | | 6 | A |
| Continuous base current | I_B | | 0.1 | A |
| Continuous device dissipation at (or below) 25°C case temperature (see Note 2) | P_{tot} | | 60 | W |
| Continuous device dissipation at (or below) 25°C free air temperature (see Note 3) | P_{tot} | | 2 | W |
| Unclamped inductive load energy (see Note 4) | $\frac{1}{2}LI_C^2$ | | 50 | mJ |
| Operating junction temperature range | T_j | | -65 to +150 | °C |
| Operating temperature range | T_{stg} | | -65 to +150 | °C |
| Operating free-air temperature range | T_A | | -65 to +150 | °C |

NOTES: 1. These values apply when the base-emitter diode is open circuited.

2. Derate linearly to 150°C case temperature at the rate of 0.48 W/°C.

3. Derate linearly to 150°C free air temperature at the rate of 16 mW/°C.

4. This rating is based on the capability of the transistor to operate safely in a circuit of: $L = 20 \text{ mH}$, $I_{B(on)} = 5 \text{ mA}$, $R_{BE} = 100 \Omega$, $V_{BE(off)} = 0$, $R_S = 0.1 \Omega$, $V_{CC} = 20 \text{ V}$.**PRODUCT INFORMATION**

electrical characteristics at 25°C case temperature (unless otherwise noted)

| PARAMETER | TEST CONDITIONS | | | MIN | TYP | MAX | UNIT |
|---|-------------------------|----------------------|------------------------|---|------------------------------|-------|------|
| V _{(BR)CEO} Collector-emitter breakdown voltage | I _C = 30 mA | I _B = 0 | (see Note 5) | BDW63 BDW63A BDW63B BDW63C BDW63D | 45 60 80 100 120 | | V |
| I _{CEO} Collector-emitter cut-off current | V _{CE} = 30 V | I _B = 0 | | BDW63 | | 0.5 | |
| | V _{CE} = 30 V | I _B = 0 | | BDW63A | | 0.5 | |
| | V _{CE} = 40 V | I _B = 0 | | BDW63B | | 0.5 | |
| | V _{CE} = 50 V | I _B = 0 | | BDW63C | | 0.5 | |
| | V _{CE} = 60 V | I _B = 0 | | BDW63D | | 0.5 | |
| I _{CBO} Collector cut-off current | V _{CB} = 45 V | I _E = 0 | | BDW63 | | 0.2 | |
| | V _{CB} = 60 V | I _E = 0 | | BDW63A | | 0.2 | |
| | V _{CB} = 80 V | I _E = 0 | | BDW63B | | 0.2 | |
| | V _{CB} = 100 V | I _E = 0 | | BDW63C | | 0.2 | |
| | V _{CB} = 120 V | I _E = 0 | | BDW63D | | 0.2 | |
| | V _{CB} = 45 V | I _E = 0 | T _C = 150°C | BDW63 | | 5 | |
| | V _{CB} = 60 V | I _E = 0 | T _C = 150°C | BDW63A | | 5 | |
| | V _{CB} = 80 V | I _E = 0 | T _C = 150°C | BDW63B | | 5 | |
| | V _{CB} = 100 V | I _E = 0 | T _C = 150°C | BDW63C | | 5 | |
| | V _{CB} = 120 V | I _E = 0 | T _C = 150°C | BDW63D | | 5 | |
| I _{EBO} Emitter cut-off current | V _{EB} = 5 V | I _C = 0 | | | | 2 | mA |
| h _{FE} Forward current transfer ratio | V _{CE} = 3 V | I _C = 2 A | (see Notes 5 and 6) | 750 | | 20000 | |
| | V _{CE} = 3 V | I _C = 6 A | | 100 | | | |
| V _{BE(on)} Base-emitter voltage | V _{CE} = 3 V | I _C = 2 A | (see Notes 5 and 6) | | | 2.5 | V |
| V _{CE(sat)} Collector-emitter saturation voltage | I _B = 12 mA | I _C = 2 A | (see Notes 5 and 6) | | | 2.5 | |
| | I _B = 60 mA | I _C = 6 A | | | | 4 | V |
| V _{EC} Parallel diode forward voltage | I _E = 6 A | I _B = 0 | | | | 3.5 | V |

NOTES: 5. These parameters must be measured using pulse techniques, t_p = 300 µs, duty cycle ≤ 2%.

6. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

thermal characteristics

| PARAMETER | MIN | TYP | MAX | UNIT |
|--|-----|-----|------|------|
| R _{θJC} Junction to case thermal resistance | | | 2.08 | °C/W |
| R _{θJA} Junction to free air thermal resistance | | | 62.5 | °C/W |

resistive-load-switching characteristics at 25°C case temperature

| PARAMETER | TEST CONDITIONS † | | | MIN | TYP | MAX | UNIT |
|--------------------------------|-------------------------------|----------------------------|---------------------------------|-----|-----|-----|------|
| t _{on} Turn-on time | I _C = 3 A | I _{B(on)} = 12 mA | I _{B(off)} = -12 mA | | 1 | | µs |
| t _{off} Turn-off time | V _{BE(off)} = -4.5 V | R _L = 10 Ω | t _p = 20 µs, dc ≤ 2% | | 5 | | µs |

† Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

PRODUCT INFORMATION

AUGUST 1978 - REVISED SEPTEMBER 2002
 Specifications are subject to change without notice.

TYPICAL CHARACTERISTICS

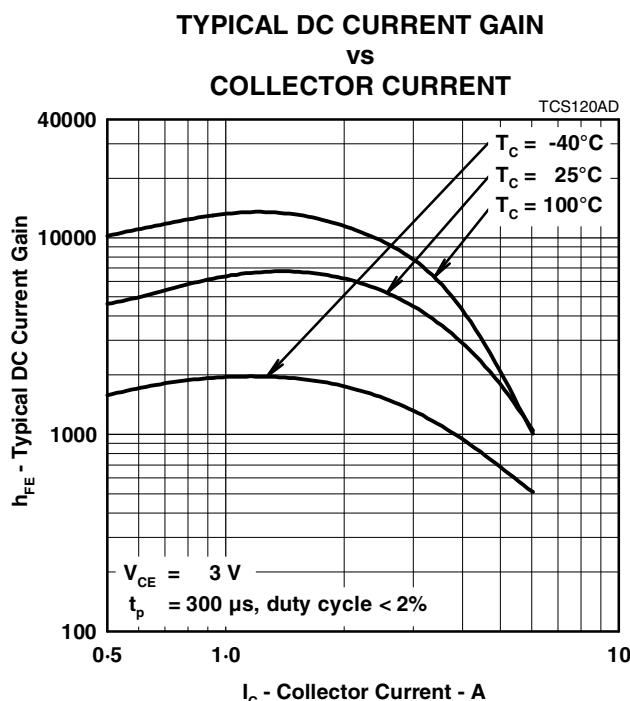


Figure 1.

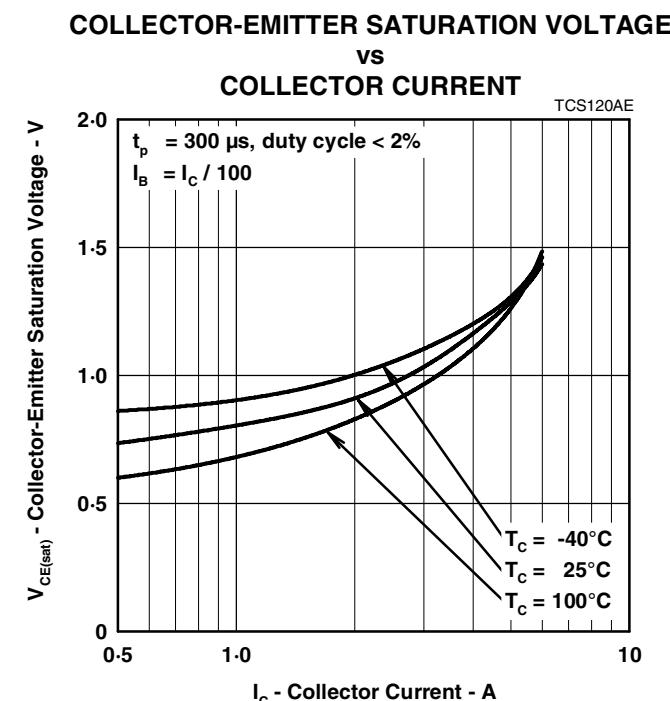


Figure 2.

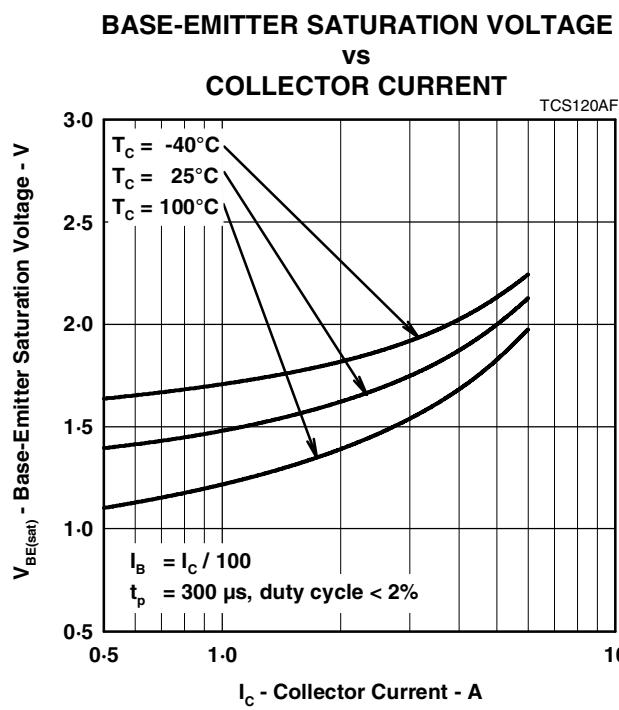


Figure 3.

PRODUCT INFORMATION

MAXIMUM SAFE OPERATING REGIONS

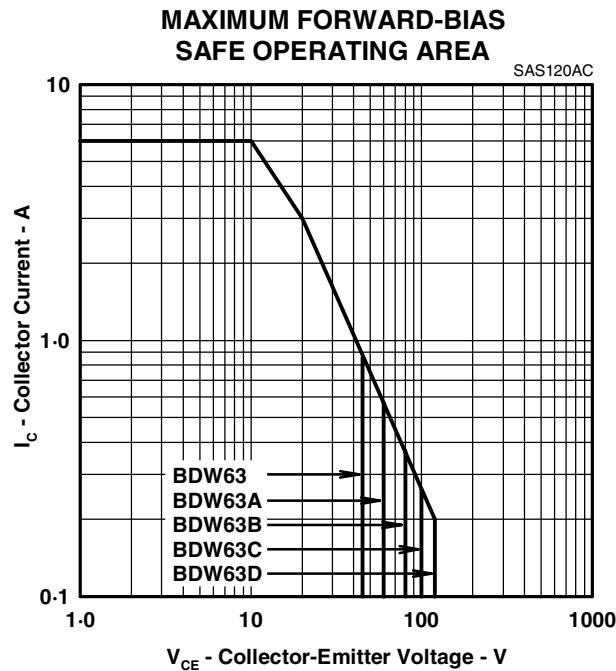


Figure 4.

THERMAL INFORMATION

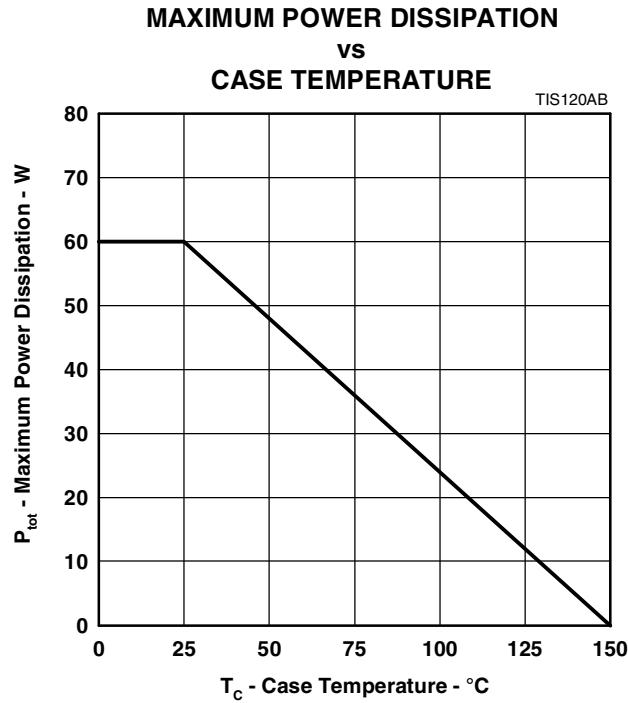


Figure 5.

PRODUCT INFORMATION

AUGUST 1978 - REVISED SEPTEMBER 2002
Specifications are subject to change without notice.